## **Declaration For U.S. Patent Application**

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled (Insert Title) Memory Device Comprising Hysteretic Capacitance Means

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the speci	ficatio	n of which is attached hereto	unless the follow	ving box is checke	ed:		
	was	filed on			As PCT International Appli	cation	
	Num		and wa	as amended on			
And/or	was : Num	filed on	and um	os amandad an	As United States Applicatio	n	
			•	as amended on		···································	
amended	by an	y amendment referred to abo	ve.		ove-identified specification,		
I acknow	ledge	the duty to disclose informat	ion which is mate	erial to patentabili	ty as defined in 37 C.F.R. §1	.56.	
below an	iu nav	foreign priority benefits und 365(a) of any PCT Internati e also identified below any date before that of the applic	toreign applicat	ion for natent or	(b) of any foreign application at least one country other the inventor's certificate or PC ed:	n(s) for patent or inventor's an the United States, listed I International Application	
(List prior		<u>JP2002-34558</u> 0	Japan (Country)	28/	November/2002	Priority Claimed  Yes No	
foreign applicat		(Number)				☐ Yes ☐ No	
		(Number)	(Country)	(Day/Mor	ath/Y car Fited)		
		(Number)	(Country)	(Day/Mor	db/Year Filed)	∐ Yes ∐ No	
I hereby o	claim t	he benefit under 35 U.S.C. §	119(e) of any Un	ited States provis	ional application(s) listed bel	ow. 	
		(Application Number)		(F1) - D.		_	
		(Application Politice)		(Filing Date)			
(List prior L	J.S.	application which is materi application and the national	al to patentability or PCT Internati	y as defined in 37 onal filing date of	the first paragraph of 35, U.S. C.F.R. §1.56 which became f this application.	available between the filing	
Applications or PCT International applications designating the U.S		(Application Serial No.)		(Filing Date)	(Status) (patented, pend	(Status) (patented, pending, abandoned)	
		(Application Serial No.)		(Filing Date)	(Status) (putented, pens	ling, abandoned)	
And I her 22,980; C David T. No. 34,79 Reg. No. Daniel D Doster, R	reby ap Charles Nikaio 94; Gr 29,21 zara, l leg. No	opoint the firm of Arent Fox M. Marmelstein, Reg. No. do, Reg. No. 22,663; Richar egory B. Kang, Reg. No. 45 1; Hans J. Crosby, Reg. No. 1; Reg. No. 47,543, Lauren b. 45,268.	, Customer Num! 25,895; George d J. Berman, Re ,273; Rustan Hi .44,634, Brian A ce J. Edson, Re	ber <b>004372</b> includ E. Oram, Jr., Reg g. No. 39,107; M I, Reg. No. 37,35 A. Tollefson, Reg g. No. 44,666; M	ling as principal attorneys: It is No. 27,931; Douglas H. Curat Ozgu, Reg. No. 44,275; I; Kevin Turner, Reg. No. 46,338, Lynne D. And lichael A. Steinberg, Reg. No.	Robert B. Murray, Reg. No. ioldhush, Reg. No. 33,125; Robert K. Carpenter, Reg. 13,437; Carl Schaukowitch, erson, Reg. No. 46,412; D. lo. 43,160; and Dinnatia J.	
Please dii	rect all	communications to the follo	wing address:	1050 Connecticut Washington, D.C	INTNER PLOTKIN & KAH It Avenue, N.W., Suite 400 C. 20036-5339 202) 857-6000; Facsimile No	,	
The unde if any, an agent, as the U.S. attorneys	rsigne id/or, i to any attorne named	d hereby authorizes the U.S. f the undersigned is not a re action to be take in the Pate ys and the undersigned. It I herein will be so notified b	attorneys named sident of the Uni nt and Trademark the event of a county the undersigned	herein to accept a ted States, the un k Office regarding change in the per l.	and follow instructions from dersigned's domestic attorne this application without dire son(s) from whom instruction	the undersigned's assignee, y, patent attorney or patent ect communication between ons may be taken, the U.S.	
I hereby of are believe made are false state	declare ved to punisl ements	that all statements made he be true; and further, that the nable by fine or imprisonme may jeopardize the validity	rein of my own kese statements we nt, or both, under of the application	mowledge are truere made with the Section 1001 of or any patent iss	e and that all statements mad knowledge that willful false Title 18 of the United States ued thereon.	e on information and belief e statements and the like so c Code and that such willful	
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